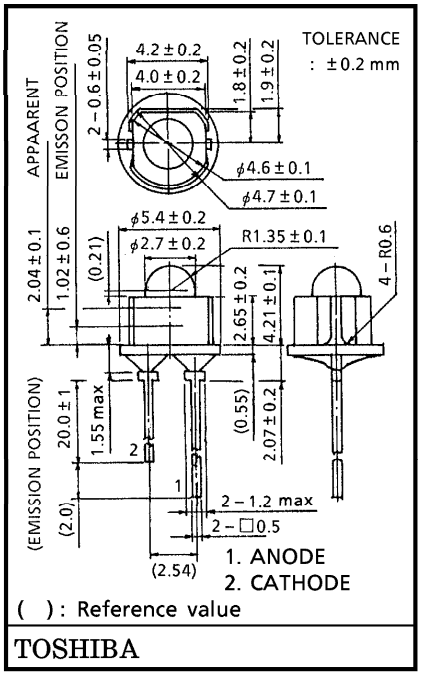
TOSHIBA LED LAMP GaAℓAs INFRARED EMITTER

TLN208

INFRARED LIGHT-EMISSION DIODE FOR STILL CAMERA

LIGHT SOURCE FOR AUTO FOCUS

Unit : mm



Weight : 0.17 g (typ.)

- Optical radiation of current confining LED chip is condensed by a resin lens.
- High output
- Effective emission diameter of 344 μm
- Optical output efficiently radiated in solid angle of 0.685 sr
- Can be operated at V_{CC} = 3 V (which is equal to is two cells)
- Optical output vs. temperature characteristic almost constant with constant forward voltage drive system

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Forward Current	(Note 1)	I_F	50	mA
Pulse Forward Current	(Note 2)	I_{FP}	400	mA
Reverse Voltage		V_R	1	V
Operating Temperature		T_{opr}	−25~60	°C
Storage Temperature		T_{stg}	−40~90	°C

(Note 1) : Permissible value for acceptance inspection / characteristic test and is guaranteed for actual application

(Note 2) : Within 4 hours at 1 cycle with frequency 10 kHz, duty 50%, power applied for 0.1 s paused for 0.4 s

OPTICAL AND ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	Min	Typ.	Max	UNIT
Forward Voltage	V_F	I_F = 50 mA	—	1.35	—	V
Pulse Forward Voltage	V_{FP}	I_{FP} = 300 mA, t = 10 ms	—	1.75	1.95	V
Reverse Current	I_R	V_R = 1 V	—	—	100	μA
Effective emission spot diameter	—	—	—	344	—	μm
Radiation Flux (Note)	ϕ_e	I_{FP} = 300 mA, t = 10 ms	7	12	—	mW
Half Value Angle	$\theta\frac{1}{2}$	I_F = 50 mA	—	54	—	°
Peak Emission Wavelength	λ_P	I_F = 50 mA	—	875	—	nm
Spectral Line Half Width	$\Delta\lambda$	I_F = 50 mA	—	40	—	nm

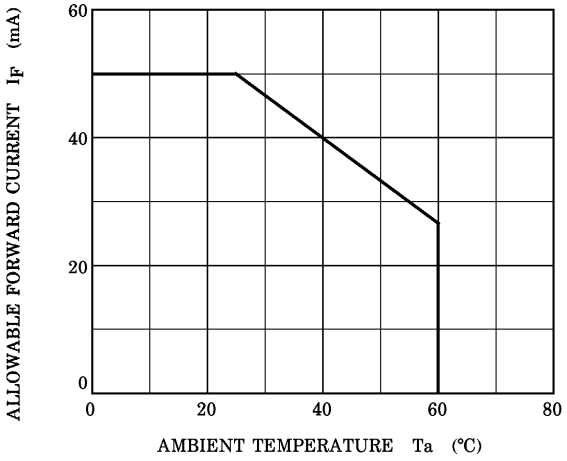
(Note) : Luminous radiation output to effective angle ±25 degree.

PRECAUTIONS

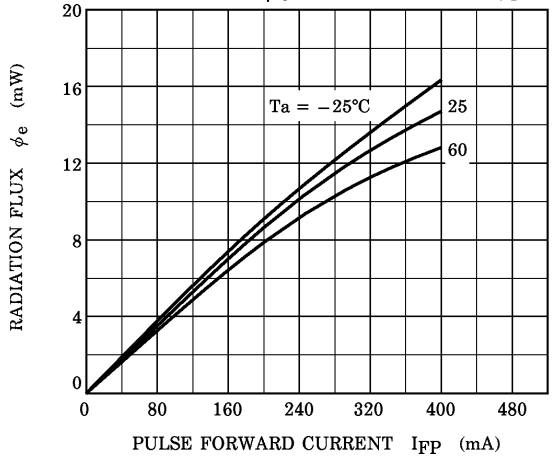
Please be careful of the followings.

1. Soldering temperature : 260°C max
   Soldering time : 5 s max
   (Soldering must be performed 1.5 m from the bottom of the package.)
2. When forming the leads, bend each lead under the 2 mm from the body of the device.
   Soldering must be performed after the leads have been formed.
3. The TLN208 for a camera AF use only. Please do not use this device except for a camera.

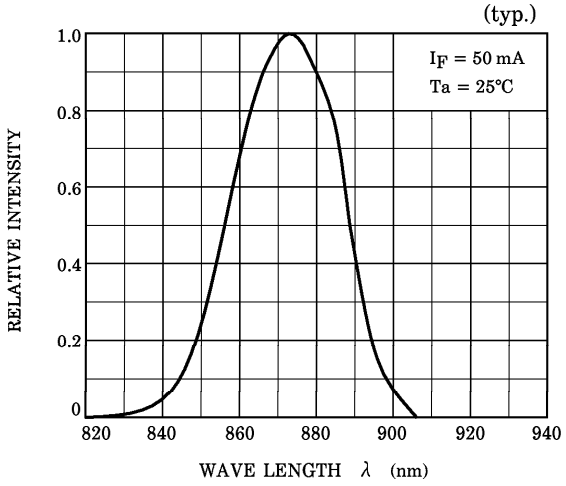
I_F – Ta



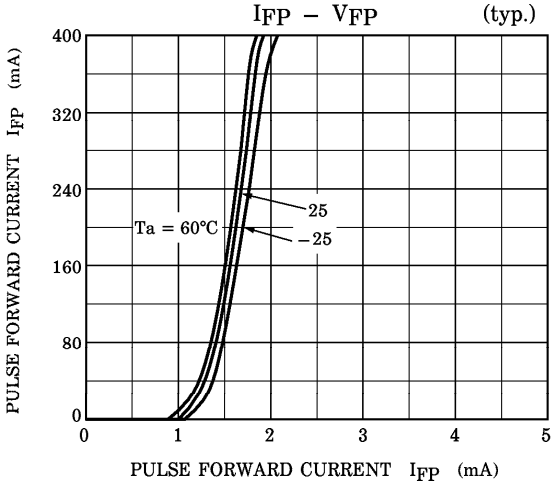
ϕ_e – I_{FP} (typ.)



WAVELENGTH CHARACTERIISTIC (typ.)

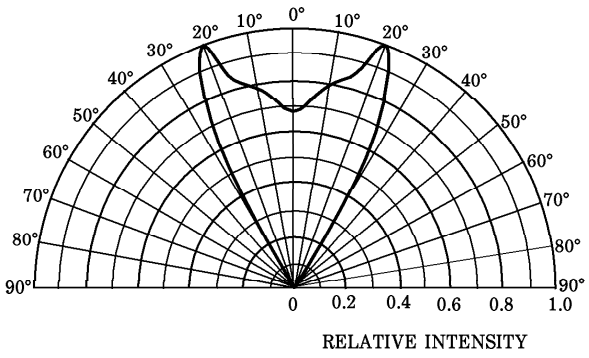


I_{FP} – V_{FP} (typ.)



RADIATION PATTERN (typ.)

(Ta = 25°C)



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